

FRED Pt® Gen 5 Hyperfast Rectifier Diode, 1200 V, 60 A



PRIMARY CHARACTERISTICS						
V _R	1200 V					
V _F (typical) at 30 A, per diode	2.91 V					
t _{rr} (typical) at 30 A, per diode	41 ns					
I _{F(DC)} per module at T _C = 85 °C	60 A					
Type	Modules - diode, FRED Pt®					
Package	SOT-227					
Circuit configuration	Two separate diodes, parallel pin-out					

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, the VS-U5FX60FA120 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		1200	V
Continuous forward current per diode	I _F	T _C = 85 °C	30	۸
Single pulse forward current per diode	I _{FSM}	T _J = 25 °C	150	Α
Maximum power dissipation per module	P_{D}	T _C = 85 °C	164	W
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 min	2500	V
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	IBOL TEST CONDITIONS MIN		TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	1200	-	-	
Forward voltage	V _{FM}	I _F = 30 A	-	2.91	3.57	V
		I _F = 30 A, T _J = 150 °C	-	2.19	-	
		V _R = 1200 V	-	0.5	60	
Reverse leakage current	I _{RM}	T _J = 125 °C, V _R = 1200 V	-	60	-	μA
		T _J = 150 °C, V _R = 1200 V	-	214	-	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time		T _J = 25 °C	$I_F = 30 \text{ A},$ $di_F/dt = 1000 \text{ A/}\mu\text{s},$ $V_R = 800 \text{ V}$	-	41	=	ns
heverse recovery time	t _{rr}	T _J = 125 °C		-	68	-	
Dook room ourrent		T _J = 25 °C		-	19	-	Α
Peak recovery current	I _{RRM}	T _J = 125 °C		-	32	-	^
Reverse recovery charge Q	0	T _J = 25 °C		-	0.8	-	uС
	Q _{rr}	T _J = 125 °C		-	2.3	=	μΟ
Junction capacitance	C _T	V _R = 1200 V, f = 1 MHz		-	13.4	-	pF

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance junction to case, per diode	D		-	-	1.1	
Thermal resistance junction to case, per module	R_{thJC}		-	-	0.55	°C/W
Thermal resistance case to heatsink, per module	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)
		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT	T-227	

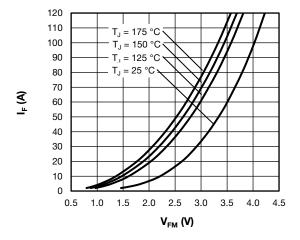


Fig. 1 - Typical Forward Voltage Drop Characteristics

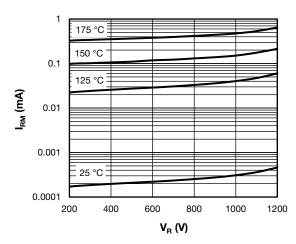


Fig. 2 - Typical Values of Reverse Current

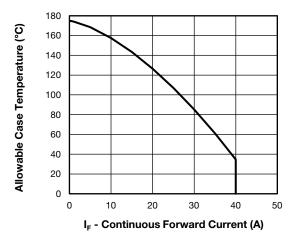


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Diode)

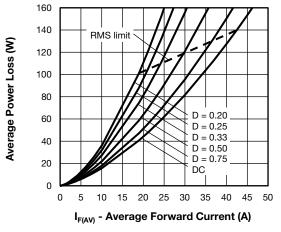


Fig. 4 - Average Power Loss vs. Average Forward Current

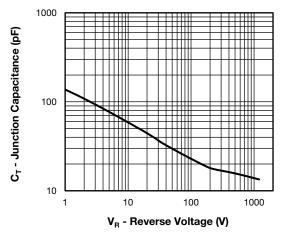


Fig. 5 - Junction Capacitance vs. Reverse Voltage

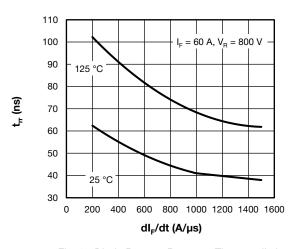


Fig. 6 - Diode Reverse Recovery Time vs. dI_Fdt

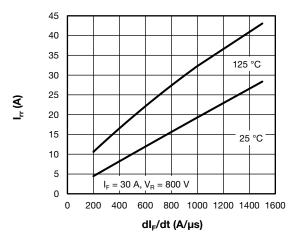


Fig. 7 - Diode Reverse Recovery Current vs. dI_Fdt

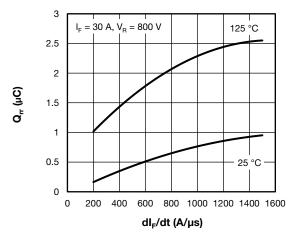


Fig. 8 - Diode Reverse Recovery Charge vs. dl_Fdt



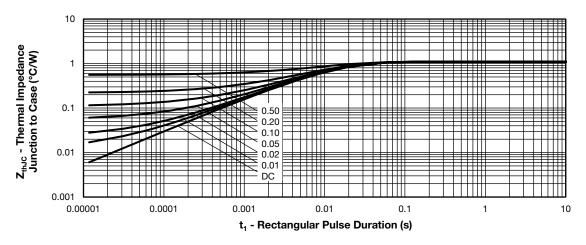


Fig. 9 - Maximum Thermal Impedance Junction to Case

ORDERING INFORMATION TABLE

1 - Vishay Semiconductors product

2 - U5F = Gen 5 FRED Pt $^{\mathbb{R}}$ family

X = Hyperfast FRED Pt[®] diode

4 - Current rating per module (60 = 60 A)

5 - F = circuit configuration (two separate diodes, parallel pin-out)

6 - Package indicator (SOT-227 standard insulated base)

7 - Voltage rating (120 = 1200 V)

CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
Two separate diodes, parallel pin-out	F	Lead Assignment 4 0 0 3 4 1 0 0 2 1			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95423			
Packaging information	www.vishay.com/doc?95425			

SOT-227 Generation 2

DIMENSIONS in millimeters (inches)





Note

· Controlling dimension: millimeter



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Vishay

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